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Vishay Semiconductors

AUTOMOTIVE

ROHS

HALOGEN

FREE

GREEN

(5-2008)

High Speed Infrared Emitting Diodes, 940 nm, GaAlAs, MQW



DESCRIPTION

VSMB2943X01 series are infrared, 940 nm emitting diodes in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

APPLICATIONS

- IrDA compatible data transmission
- · Miniature light barrier
- IR touch panels
- 3D TV
- Photointerrupters
- · Optical switch
- · Control and drive circuits
- Shaft encoders

FEATURES

Package type: surface-mount

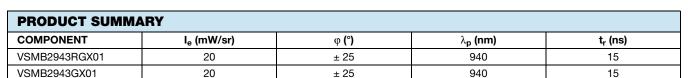
• Package form: GW, RGW



AEC-Q101 qualified

• Peak wavelength: $\lambda_p = 940 \text{ nm}$

- High reliability
- · High radiant power
- High radiant intensity
- Angle of half intensity: $\varphi = \pm 25^{\circ}$
- Low forward voltage
- · Suitable for high pulse current operation
- · Terminal configurations: gullwing or reserve gullwing
- Package matches with detector VEMD2xx3X01 and VEMT2xx3X01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
VSMB2943RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing			
VSMB2943GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing			

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V_{R}	5	V		
Forward current		I _F	100	mA		
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA		
Surge forward current	t _p = 100 μs	I _{FSM}	1	Α		
Power dissipation		P _V	160	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T _{amb}	-40 to +85	°C		
Storage temperature range		T _{stg}	-40 to +100	°C		
Soldering temperature	according figure 9, J-STD-020	T _{sd}	260	°C		
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	250	K/W		

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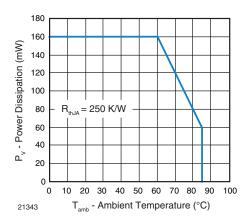


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

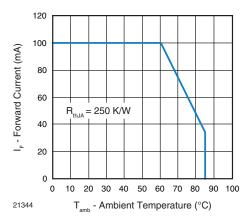


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP. MAX.		UNIT	
Farmer describer of	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F	1.15	1.35	1.6	V	
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V_{F}		2.2		V	
Tamana and the analysis and a five	I _F = 1 mA	TK _{VF}		-1.8		mV/K	
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}		-1.1		mV/K	
Reverse current		I _R	Not designed for reverse operation			μΑ	
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ		70		pF	
B #	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	10	20	30	mW/sr	
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	I _e		170		mW/sr	
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe		40		mW	
Temperature coefficient of radiant	I _F = 1 mA	TKφ _e		-1.1		%/K	
power	I _F = 100 mA	TKφ _e		-0.51		%/K	
Angle of half intensity		φ		± 25		0	
Peak wavelength	I _F = 30 mA	λ_{p}	920	940	960	nm	
Spectral bandwidth	I _F = 30 mA	Δλ		25		nm	
Temperature coefficient of λ_p	I _F = 30 mA	TKλ _p		0.25		nm/K	
Rise time	I _F = 100 mA, 20 % to 80 %	t _r		15		ns	
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		15		ns	
Cut-off frequency	I _{DC} = 70 mA, I _{AC} = 30 mA pp	f _c		23		MHz	

I_F = 1 mÅ

180

160

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

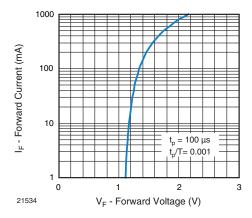
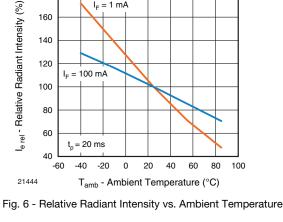


Fig. 3 - Forward Current vs. Forward Voltage



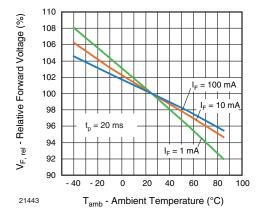


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

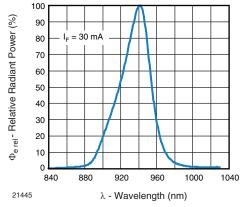


Fig. 7 - Relative Radiant Power vs. Wavelength

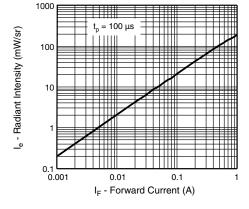


Fig. 5 - Radiant Intensity vs. Forward Current

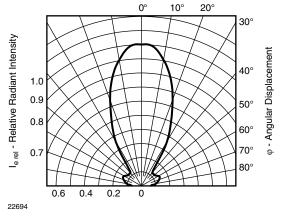


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

SOLDER PROFILE

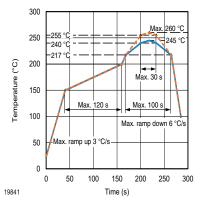


Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

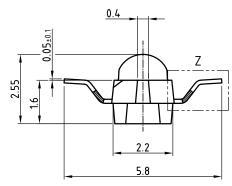
FLOOR LIFE

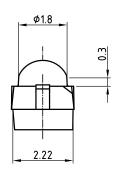
Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 4 weeks Conditions: T_{amb} < 30 °C, RH < 60 % Moisture sensitivity level 2a, acc. to J-STD-020.

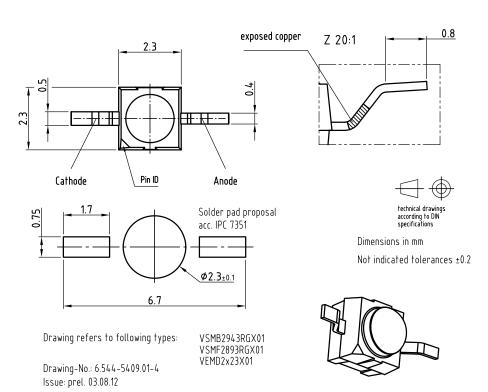
DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ C.

PACKAGE DIMENSIONS in millimeters: VSMB2943RG





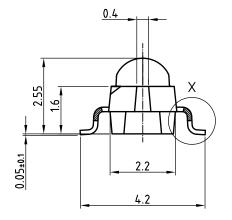


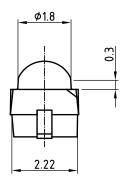


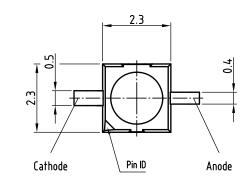
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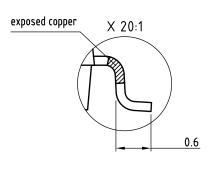
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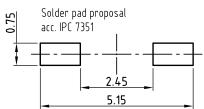
PACKAGE DIMENSIONS in millimeters: VSMB2943G













Not indicated tolerances ±0.2

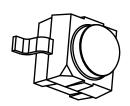
Drawing refers to following types:

VSMB2943GX01

Drawing-No.: 6.544-5408.01-4

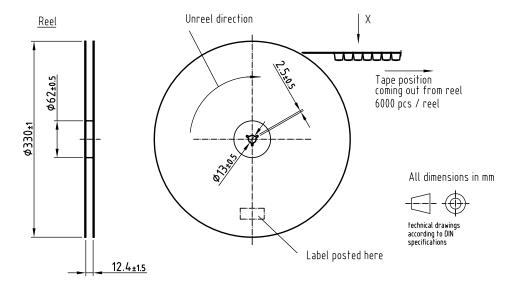
Issue: prel; 03.08.12

VSMF2893GX01 VEMD2x23X01

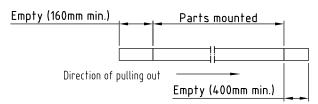


Dimensions in mm

TAPING AND REEL DIMENSIONS in millimeters: VSMB2943RG

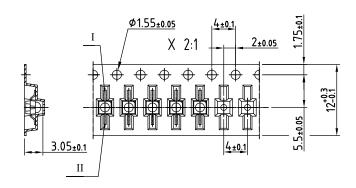


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II
VSMB2943RGX01		
VSMF2893RGX01	Cathode	Anode
VEMD2x03X01	carnoue	Alloue
VEMT2x03X01	Collector	Emitter
	CONSCION	riiirrei
VSMY2853RG	Anode	Cathode

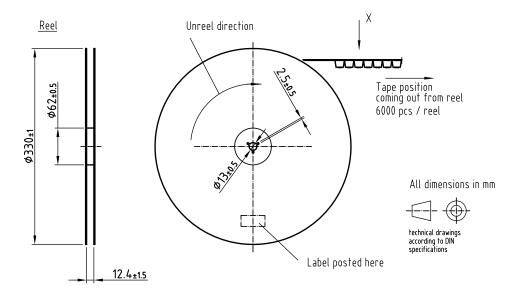


Drawing refers to following types: Reel dimensions and tape

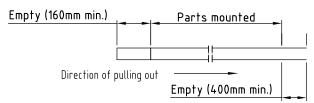
see table

Drawing-No.: 9.800-5100.02-4 Issue: prel; 03.08.12

TAPING AND REEL DIMENSIONS in millimeters: VSMB2943G



Leader and trailer tape:



Terminal position in tape			\$\\\phi 1.55 \pm 0.05	4±0.1		
Device	Lead I	Lead II	<u> </u>	/ X 2:1	2±0.05	
VSMB2943GX01			. \ .	1		
VSMF2893GX01	Cathode	Anode		θ θ θ θ		
VEMD2x23X01	Carnode	Carriode	Alloue			$^{\circ}$
					╎ ┞ ┡╏╏ ┡╏╏	
VEMT2x23X01	Collector	Emitter				
	Cottector	or Elimitel	b		- . 	
VSMY2853G	Anode	Cathode	3.05±0.1		4±0.1	
			II			

Drawing refers to following types: see table Reel dimensions and tape

Drawing-No.: 9.800-5091.21-4 Issue: prel; 03.08.12



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